TOSHIBA Photocoupler Photorelay

TLP4176G

PBX

Telecommunication

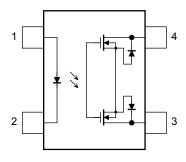
Modem·FAX Cards, Modems In PC

Measurement Instrumentation

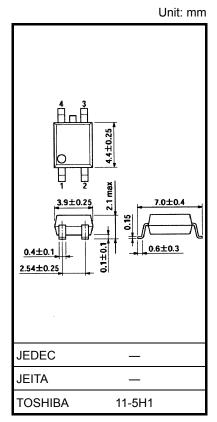
The TOSHIBA TLP4176GA consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a SOP, which is suitable for surface mount assembly.

- 4 pin SOP (2.54SOP4): 2.1 mm high, 2.54 mm pitch
- 1-form-B
- Peak off-state voltage: 350 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 120 mA (max)
- On-state resistance: 25Ω (max)
- Isolation voltage: 1500 Vrms (min)

Pin Configuration (top view)



- 1: ANODE
- 2: CATHODE
- 3: DRAIN
- 4: DRAIN



Weight: 0.1 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

| | Characteristics | Symbol | Rating | Unit |
|--|--|----------------------|------------|-------|
| | Forward current | lF | 50 | mA |
| | Forward current derating (Ta ≥ 25°C) | ΔI _F /°C | -0.5 | mA/°C |
| LED | Peak forward current (100 μs pulse, 100 pps) | I _{FP} | 1 | Α |
| | Reverse voltage | V_{R} | 5 | V |
| | Junction temperature | Tj | 125 | °C |
| | Off-state output terminal voltage | V _{OFF} | 350 | V |
| tor | On-state current | I _{ON} | 120 | mA |
| Detector | On-state current derating (Ta ≥ 25°C) | Δl _{ON} /°C | -1.2 | mA/°C |
| | Junction temperature | Tj | 125 | °C |
| Operating temperature range | | T _{opr} | -40 to 85 | °C |
| Storage temperature range | | T _{stg} | -55 to 125 | °C |
| Lead soldering temperature (10 s) | | T _{sol} | 260 | °C |
| $ \begin{array}{ll} \text{Isolation voltage} \\ \text{(AC, 1 min, R.H.} \leq 60\%) & \text{(Note 1)} \end{array} $ | | BVS | 1500 | Vrms |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two-terminal device: LED side pins shorted together, and DETECTOR side pins shorted together.

Recommended Operating Conditions

| Characteristics | Symbol | Min | Тур. | Max | Unit |
|-----------------------|------------------|-----|------|-----|------|
| Supply voltage | V_{DD} | _ | _ | 280 | V |
| Forward current | lF | 5 | _ | 25 | mA |
| On-state current | I _{ON} | _ | _ | 120 | mA |
| Operating temperature | T _{opr} | -20 | _ | 65 | °C |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

| | Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---------------|-------------------|------------------|---|-----|------|-----|------|
| CED | Forward voltage | V_{F} | I _F = 10 mA | 1.0 | 1.15 | 1.3 | V |
| | Reverse current | I _R | V _R = 5 V | _ | _ | 10 | μА |
| | Capacitance | C _T | V = 0, f = 1 MHz | _ | 30 | _ | pF |
| Detec- tor | Off-state current | loff | $V_{OFF} = 350 \text{ V}, I_F = 5 \text{ mA}$ | _ | _ | 1 | μΑ |
| | Capacitance | C _{OFF} | $V = 0$, $f = 1$ MHz, $I_F = 5$ mA | | _ | | pF |

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Coupled Electrical Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---------------------|-----------------|--------------------------|-----|------|-----|------|
| Trigger LED current | I _{FC} | I _{OFF} = 10 μA | _ | 1 | 3 | mA |
| Return LED current | I _{FT} | I _{ON} = 120 mA | 0.1 | _ | _ | mA |
| On-state resistance | R _{ON} | I _{ON} = 120 mA | _ | 15 | 25 | Ω |

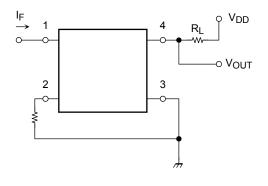
Isolation Characteristics (Ta = 25°C)

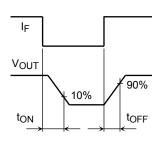
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-----------------------------|--------------------------------|------------------------------------|--------------------|------------------|--------|------|
| Capacitance input to output | Cs | V _S = 0, f = 1 MHz | _ | 8.0 | _ | pF |
| Isolation resistance | R _S | V _S = 500 V, R.H. ≦ 60% | 5×10^{10} | 10 ¹⁴ | _ | Ω |
| | AC, 1 min BVs AC, 1 s, in oil | AC, 1 min | 1500 | _ | _ | Vrms |
| Isolation voltage | | _ | 3000 | _ | VIIIIS | |
| | | DC, 1 min, in oil | _ | 3000 | _ | Vdc |

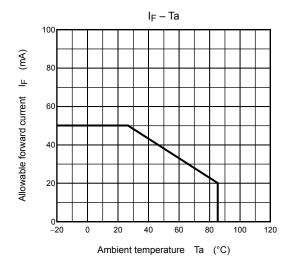
Switching Characteristics (Ta = 25°C)

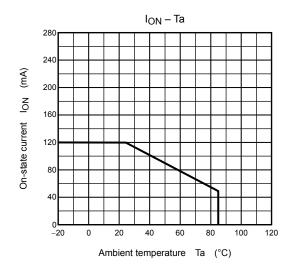
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-----------------|-----------------|---|-----|------|-----|------|
| Turn-on time | t _{ON} | $R_L = 200 \Omega$ (Note 2) | _ | _ | 1 | ms |
| Turn-off time | toff | $V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$ | _ | _ | 3 | ms |

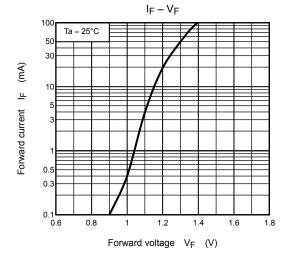
Note 2: Switching time test circuit

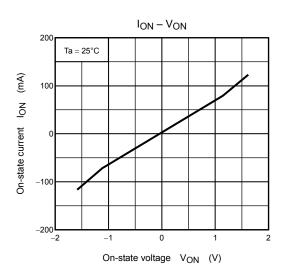


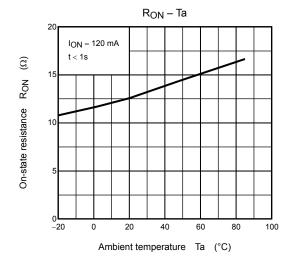


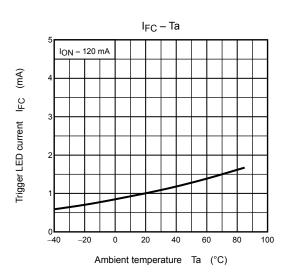




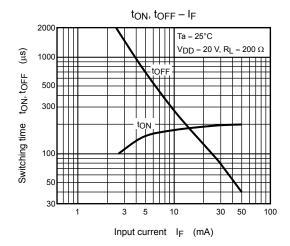


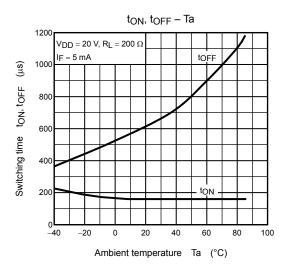


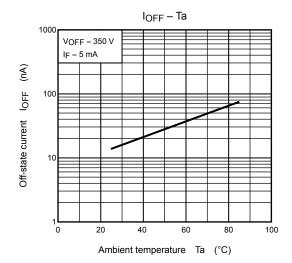




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